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DESCRIPTION

A4809 is a series of high precision voltage detector with ultra-low current consumption (4.5uA typ. at V_{IN} =3.0V) and a built-in delay circuit. It can work at very low voltage, which makes it perfect for system reset.

A4809 is composed of high precision voltage reference, comparator, delay circuit, output driver and resistor array. Internally preset detect voltage has a low temperature drift and requires no external trimming.

Two type of output, CMOS and N-channel open-drain are available.

A4809 is available in SOT-23S package.

FEATURES

- High-Precision Detection Voltage: ±3%
- Detection Voltage : 2.63V and 2.93V (customized other voltages)
- Built-in Power on Reset Delay time circuit: Refer to Selection Guide
- Operating Voltage Range:1.2V~6V
- Ultra-low current consumption: 4.5uA typ. (at V_{IN} = 3.0V)
- Two Output Forms: CMOS (Active Low) and N-channel open-drain (Active Low)
- Available in SOT-23S package

APPLICATION

- Power monitor for portable equipment such as PDA, DSC, Mobile phone,Notebook,MP3
- CPU and Logic Circuit Reset
- Battery Checker
- Battery Back-up Circuit
- Power Failure Detector

TYPICAL APPLICATION



ORDERING INFORMATION

Package Type	Part Number		
SOT-23S	F 20	A4809E3SR-XXXDZY	
SPQ: 3,000pcs/Reel	E3S	A4809E3SVR-XXXDZY	
	XXX: Detector Voltage		
	263=2.63V; 293=2.93V		
	D: Delay Time; 200ms		
	Z: C=CMOS, N=Nch		
Note	Y: Pin Type		
	None: Type A		
	В: Туре В		
	V: Halogen Free Package		
	R: Tape & Reel		
AiT provides all RoHs products			



PIN DESCRIPTION



ABSOLUTE MAXIMUM RATINGS

Input Voltage	-0.3V~8V
Output Voltage Range	-0.3V~8V
Maximum Output Current	70mA
T _A , Ambient Temperature	-40°C~+85°C
Power Dissipation	250mW
Ts, Storage Temperature	-40°C~+150°C
Lead Temperature & Time	260°C, 10s

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



RECOMMENDED WORK CONDITIONS

Parameter	Min.	Recommended	Max.	Unit
Input Voltage Range	1.2		6	V
Ambient Temperature	-40	25	85	°C

ELECTRICAL CHARACTERISTICS

A4809xR-263DZx (2.63V)

Topt = 25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Detector Threshold	-V _{DET}		2.551	2.63	2.709	V
Current Consumption	lss	V _{DD} =4.63V	-	4.5	10	μA
Maximum Operating Voltage	V _{DDH}		-	-	10	V
Minimum Operating Voltage	VDDL		-	0.5	-	V
Output Current	Іоит	Pch V_{DS} =-2.1V , V_{DD} =4.5V	1.0	2.0	-	mA

A4809xR-293DZx (2.93V)

Topt = 25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Detector Threshold	-V _{DET}		2.842	2.93	3.018	V
Current Consumption	lss	V _{DD} =4.93V	-	4.5	10	μA
Maximum Operating Voltage	V _{DDH}		-	-	10	V
Minimum Operating Voltage	VDDL		-	0.5	-	V
Output Current	Ιουτ	Pch V _{DS} =-2.1V , V _{DD} =4.5V	1.0	2.0	-	mA

ELECTRICAL CHARACTERISTICS BY OUTPUT DELAY TIME

Deremeter	Oanditiona	Output Delay Time			11
Parameter	Conditions	Min.	Тур.	Max.	Unit
Delay time	V _{DD} =1.0V to V _{DET} +1.0V	140	200	300	ms



TYPICAL PERFORMANCE CHARACTERISTICS





3. Nch Driver Output Current vs. V_{DS} Detector threshold=2.93V



5. Pch Driver Output Current vs. Input Voltage Detector threshold=2.93V



2. Detector Threshold vs. Temperature Detector threshold=2.93V



4. Nch Driver Output Current vs. Input Voltage Detector threshold=2.93V





TEST CIRCUITS

1. Supply current test circuit



3. Nch Drive Output Current Test Circuit



2. Detector threshold test circuit



4. Pch Drive Output Current Test Circuit





BLOCK DIAGRAM



N Channel Open Drain



FUNCTION DESCRIPTION



High precision low temperature co-efficiency reference voltage is applied to the negative input of a comparator. Input voltage, divided by resistor array of Ra and Rb, is applied to the positive input of the comparator. Output of the comparator passes a delay circuit and a series of buffer to drive the output CMOS pair.

VDET =VREF*(1+Ra/Rb)



No.	Operation status	Output status
I	V _{DD} >V _{DET}	Output voltage is equal to the supply voltage
Ш	V_{DD} drops below V_{DET}	Output voltage equals to GND level
Ш	VDD drops further below VDDL	Output voltage is undefined
IV	V _{DD} rises above V _{DDL}	Output voltage equals to GND level
V	V_{DD} rises above V_{DET}	Output voltage equals to supply voltage after $t_{\mbox{\scriptsize DELAY}}$



PACKAGE INFORMATION

Dimension in SOT-23S Package (Unit: mm)





IMPORTANT NOTICE

AiT Semiconductor Inc. (AiT) reserves the right to make changes to any its product, specifications, to discontinue any integrated circuit product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

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